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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

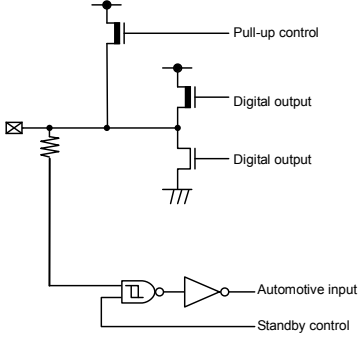
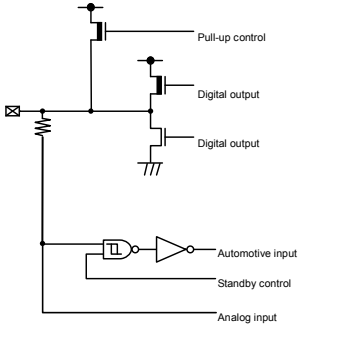
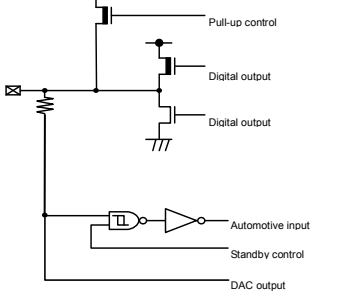
Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	FR81S
Core Size	32-Bit Single-Core
Speed	80MHz
Connectivity	CANbus, CSIO, I ² C, LINbus, SPI, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	76
Program Memory Size	448KB (448K x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	56K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 37x12b; D/A 2x8b
Oscillator Type	External
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb91f523fwcpmc-gse1

- D/A converter (R-2R type)
 - 8-bit resolution : 2ch
- External interrupt input: 8 channels × 2 units total 16 channels
 - Level ("H" / "L"), or edge detection (rising or falling) enabled
- Multi-function serial communication (built-in transmission/reception FIFO memory) : Max.12 channels
 - 5V tolerant input: 4 channels ch.6, ch.8, ch.9, ch.11 CMOS hysteresis input < UART (Asynchronous serial interface) >
 - Full-duplex double buffering system, 64-step transmission FIFO memory, 64-step reception FIFO memory
 - Parity or no parity is selectable.
 - Built-in dedicated baud rate generator
 - An external clock can be used as the transfer clock
 - Parity, frame, and overrun error detection functions provided
 - DMA transfer support <CSIO (Synchronous serial interface) >
 - Full-duplex double buffering system, 64-step transmission FIFO memory, 64-step reception FIFO memory
 - SPI supported; master and slave systems supported; 5 to 16, 20, 24, 32-bit data length can be set.
 - Built-in dedicated baud rate generator (Master operation)
 - An external clock can be entered. (Slave operation)
 - Overrun error detection function is provided
 - DMA transfer support
 - Serial chip select SPI function <LIN (Asynchronous Serial Interface for LIN) >
 - Full-duplex double buffering system, 64-step transmission FIFO memory, 64-step reception FIFO memory
 - LIN protocol revision 2.1 supported
 - Master and slave systems supported
 - Framing error and overrun error detection
 - LIN synch break generation and detection; LIN synch delimiter generation
 - Built-in dedicated baud rate generator
 - An external clock can be adjusted by the reload counter
 - DMA transfer support
 - Hard assist function < I²C >
 - 2 channels ch.3 , ch.4 Standard mode/fast mode supported.
 - 6 channels ch.5 to ch.8, ch.10, ch.11 Standard mode supported.
 - Full-duplex double buffering system, 64-step transmission FIFO memory, 64-step reception FIFO memory
 - Standard mode (Max. 100kbps) / fast mode (Max. 400kbps) supported
 - DMA transfer supported (for transmission only)
- CAN Controller (CAN) : 3 channels
 - Transfer speed : Up to 1Mbps
 - 128-transmission/reception message buffering : 1 channel (ch.0), 64-transmission/reception message buffering : 2 channels (ch.1 and ch.2)
- PPG: 16-bit × Max. 48 channels
 - LED drive output 4 channels 11ch to 14ch
 - Reload timer : 16-bit × Max.8 channels
 - Free-run timer : 16-bit × 3 channels 32-bit × Max 3 channels
- Input capture :
 - 16-bit × 4 channels (linked to the free-run timer)
 - 32-bit × Max 6 channels (linked to the free-run timer)
- Output compare :
 - 16-bit × 6 channels (linked to the free-run timer)
 - 32-bit × Max 6 channels (linked to the free-run timer)
- Waveform generator : 6 channels
- Up/Down counter
 - 8/16-bit Up/Down counter × 2 channels
- Real-time clock (RTC) (for day, hours, minutes, seconds)
 - Main or sub oscillation frequency can be selected for the operation clock
- Calibration: Real-time clock (RTC) of the subclock drive
 - The main clock to sub clock ratio can be corrected by setting the real-time clock prescaler
- Clock Supervisor
 - Monitoring abnormality (by damaged quartz, etc.) of suboscillation (32kHz) (dual clock products) of the outside and main oscillation (4 MHz)
 - When abnormality is detected, it switches to the CR clock.
 - Initial value ON/OFF can be selected by the part number.
- Base timer : Max.2 channels
 - 16-bit timer
 - Any of four PWM/PPG/PWC/reload timer functions can be selected and used
 - As for the PWC function and the reload timer function, a pair of 16-bit timers can be used as one 32-bit timer in the cascade mode
- CRC generation
- Watchdog timer
 - Hardware watchdog
 - Software watchdog (possible to set the valid range for counter clearing)
- NMI (non-maskable interrupt)
- Interrupt controller
- Interrupt request batch read
 - The interrupt existence from two or more peripherals can be read by a series of register.
- I/O relocation
 - Peripheral function pins can be reassigned.
- Low-power consumption mode
 - Sleep / Stop / Watch / Sub RUN mode
 - Stop (power shutdown) / Watch (power shutdown) mode

4. I/O Circuit Type

Type	Circuit	Remarks
A		•General-purpose I/O port •Output 4mA •Pull-up resistor control 50kΩ •Automotive input
B		•Analog input, General-purpose I/O port •Output 4mA •Pull-up resistor control 50kΩ •Automotive input
C		•DAC output, General-purpose I/O port •Output 4mA •Pull-up resistor control 50kΩ •Automotive input

5. Handling Precautions

Any semiconductor devices have inherently a certain rate of failure. The possibility of failure is greatly affected by the conditions in which they are used (circuit conditions, environmental conditions, etc.). This page describes precautions that must be observed to minimize the chance of failure and to obtain higher reliability from your Cypress semiconductor devices.

1. Precautions for Product Design

This section describes precautions when designing electronic equipment using semiconductor devices.

■ Absolute Maximum Ratings

Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of certain established limits, called absolute maximum ratings. Do not exceed these ratings.

■ Recommended Operating Conditions

Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their sales representative beforehand.

■ Processing and Protection of Pins

These precautions must be followed when handling the pins which connect semiconductor devices to power supply and input/output functions.

(1) Preventing Over-Voltage and Over-Current Conditions

Exposure to voltage or current levels in excess of maximum ratings at any pin is likely to cause deterioration within the device, and in extreme cases leads to permanent damage of the device. Try to prevent such overvoltage or over-current conditions at the design stage.

(2) Protection of Output Pins

Shorting of output pins to supply pins or other output pins, or connection to large capacitance can cause large current flows. Such conditions if present for extended periods of time can damage the device. Therefore, avoid this type of connection.

(3) Handling of Unused Input Pins

Unconnected input pins with very high impedance levels can adversely affect stability of operation. Such pins should be connected through an appropriate resistance to a power supply pin or ground pin.

■ Latch-up

Semiconductor devices are constructed by the formation of P-type and N-type areas on a substrate. When subjected to abnormally high voltages, internal parasitic PNP junctions (called thyristor structures) may be formed, causing large current levels in excess of several hundred mA to flow continuously at the power supply pin. This condition is called latch-up.

CAUTION: The occurrence of latch-up not only causes loss of reliability in the semiconductor device, but can cause injury or damage from high heat, smoke or flame. To prevent this from happening, do the following:

- (1) Be sure that voltages applied to pins do not exceed the absolute maximum ratings. This should include attention to abnormal noise, surge levels, etc.
- (2) Be sure that abnormal current flows do not occur during the power-on sequence.

Address	Address offset value / Register name				Block
	+0	+1	+2	+3	
0008A0 _H	WRAR04 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				Wild Register [S]
0008A4 _H	WRDR04 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008A8 _H	WRAR05 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				
0008AC _H	WRDR05 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008B0 _H	WRAR06 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				
0008B4 _H	WRDR06 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008B8 _H	WRAR07 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				
0008BC _H	WRDR07 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008C0 _H	WRAR08 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				
0008C4 _H	WRDR08 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008C8 _H	WRAR09 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				
0008CC _H	WRDR09 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008D0 _H	WRAR10 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				
0008D4 _H	WRDR10 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008D8 _H	WRAR11 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				
0008DC _H	WRDR11 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008E0 _H	WRAR12 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				
0008E4 _H	WRDR12 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008E8 _H	WRAR13 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				
0008EC _H	WRDR13 [R/W] W XXXXXXXX XXXXXXXXXX XXXXXXXXXX XXXXXXXXXX				
0008F0 _H	WRAR14 [R/W] W ----- --XXXXXX XXXXXXXXXX XXXXXX--				

Address	Address offset value / Register name				Block
	+0	+1	+2	+3	
0013E8 _H	ADTECS14[R/W] B,H,W -----0 ---00000		ADTECS15[R/W] B,H,W -----0 ---00000		12-bit A/D converter 1/2 unit
0013EC _H	ADTECS16[R/W] B,H,W -----0 ---00000		ADTECS17[R/W] B,H,W -----0 ---00000		
0013F0 _H	ADTECS18[R/W] B,H,W -----0 ---00000		ADTECS19[R/W] B,H,W -----0 ---00000		
0013F4 _H	ADTECS20[R/W] B,H,W -----0 ---00000		ADTECS21[R/W] B,H,W -----0 ---00000		
0013F8 _H	ADTECS22[R/W] B,H,W -----0 ---00000		ADTECS23[R/W] B,H,W -----0 ---00000		
0013FC _H	ADTECS24[R/W] B,H,W -----0 ---00000		ADTECS25[R/W] B,H,W -----0 ---00000		
001400 _H	ADTECS26[R/W] B,H,W -----0 ---00000		ADTECS27[R/W] B,H,W -----0 ---00000		
001404 _H	ADTECS28[R/W] B,H,W -----0 ---00000		ADTECS29[R/W] B,H,W -----0 ---00000		
001408 _H	ADTECS30[R/W] B,H,W -----0 ---00000		ADTECS31[R/W] B,H,W -----0 ---00000		
00140C _H	ADRCUT0[R/W] B,H,W ----0000 00000000		ADRCLT0[R/W] B,H,W ----0000 00000000		
001410 _H	ADRCUT1[R/W] B,H,W ----0000 00000000		ADRCLT1[R/W] B,H,W ----0000 00000000		
001414 _H	ADRCUT2[R/W] B,H,W ----0000 00000000		ADRCLT2[R/W] B,H,W ----0000 00000000		
001418 _H	ADRCUT3[R/W] B,H,W ----0000 00000000		ADRCLT3[R/W] B,H,W ----0000 00000000		
00141C _H	ADRCSS0[R/W] B,H,W 00000000	ADRCSS1[R/W] B,H,W 00000000	ADRCSS2[R/W] B,H,W 00000000	ADRCSS3[R/W] B,H,W 00000000	
001420 _H	ADRCSS4[R/W] B,H,W 00000000	ADRCSS5[R/W] B,H,W 00000000	ADRCSS6[R/W] B,H,W 00000000	ADRCSS7[R/W] B,H,W 00000000	
001424 _H	ADRCSS8[R/W] B,H,W 00000000	ADRCSS9[R/W] B,H,W 00000000	ADRCSS10[R/W] B,H,W 00000000	ADRCSS11[R/W] B,H,W 00000000	
001428 _H	ADRCSS12[R/W] B,H,W 00000000	ADRCSS13[R/W] B,H,W 00000000	ADRCSS14[R/W] B,H,W 00000000	ADRCSS15[R/W] B,H,W 00000000	
00142C _H	ADRCSS16[R/W] B,H,W 00000000	ADRCSS17[R/W] B,H,W 00000000	ADRCSS18[R/W] B,H,W 00000000	ADRCSS19[R/W] B,H,W 00000000	
001430 _H	ADRCSS20[R/W] B,H,W 00000000	ADRCSS21[R/W] B,H,W 00000000	ADRCSS22[R/W] B,H,W 00000000	ADRCSS23[R/W] B,H,W 00000000	

Address	Address offset value / Register name				Block
	+0	+1	+2	+3	
001804 _H	—	—/(SCSFR24) [R/W] B,H,W ----- ^{*3}	—/(SCSFR14) [R/W] B,H,W ----- ^{*3}	—/(SCSFR04) [R/W] B,H,W ----- ^{*3}	Multi-UART4 *3: Reserved because CSIO mode is not set immediately after reset. *4: Reserved because LIN2.1 mode is not set immediately after reset.
001808 _H	—/(TBYTE34)/ (LAMESR4) [R/W] B,H,W ----- ^{*3}	—/(TBYTE24)/ (LAMERT4) [R/W] B,H,W ----- ^{*3}	—/(TBYTE14)/ (LAMIER4) [R/W] B,H,W ----- ^{*3}	TBYTE04/(LAMRID4) / (LAMTID4) [R/W] B,H,W 00000000	
00180C _H	BGR4[R/W] H, W 00000000 00000000		—/(ISMK4)[R/W] B,H,W ----- ^{*2}	—/(ISBA4)[R/W] B,H,W ----- ^{*2}	
001810 _H	FCR14[R/W] B,H,W ---00100	FCR04[R/W] B,H,W -0000000	FBYTE4[R/W] B,H,W 00000000 00000000		
001814 _H	FTICR4[R/W] B,H,W 00000000 00000000		—	—	
001818 _H	SCR5/(IBCR5) [R/W] B,H,W 0--00000	SMR5[R/W] B,H,W 000-00-0	SSR5[R/W] B,H,W 0-000011	ESCR5/(IBSR5)[R/W]] B,H,W 00000000	Multi-UART5 *1: Byte access is possible only for access to lower 8 bits. *2: Reserved because I ² C mode is not set immediately after reset. *3: Reserved because CSIO mode is not set immediately after reset. *4: Reserved because LIN2.1 mode is not set immediately after reset.
00181C _H	—/(RDR15/(TDR15))[R/W] B,H,W ----- ^{*3}		RDR05/(TDR05)[R/W] B,H,W -----0 00000000 ^{*1}		
001820 _H	SACSR5[R/W] B,H,W 0----000 00000000		STMR5[R] B,H,W 00000000 00000000		
001824 _H	STMCR5[R/W] B,H,W 00000000 00000000		—/(SCSCR5/SFUR5)[R/W] B,H,W ----- ^{*3} ^{*4}		
001828 _H	—/(SCSTR35)/ (LAMSR5) [R/W] B,H,W ----- ^{*3}	—/(SCSTR25)/ (LAMCR5) [R/W] B,H,W ----- ^{*3}	—/(SCSTR15)/ (SFLR15) [R/W] B,H,W ----- ^{*3}	—/(SCSTR05)/ (SFLR05) [R/W] B,H,W ----- ^{*3}	
00182C _H	—	—/(SCSFR25) [R/W] B,H,W ----- ^{*3}	—/(SCSFR15) [R/W] B,H,W ----- ^{*3}	—/(SCSFR05) [R/W] B,H,W ----- ^{*3}	
001830 _H	—/(TBYTE35)/ (LAMESR5) [R/W] B,H,W ----- ^{*3}	—/(TBYTE25)/ (LAMERT5) [R/W] B,H,W ----- ^{*3}	—/(TBYTE15)/ (LAMIER5) [R/W] B,H,W ----- ^{*3}	TBYTE05/(LAMRID5) / (LAMTID5) [R/W] B,H,W 00000000	
001834 _H	BGR5[R/W] H, W 00000000 00000000		—/(ISMK5)[R/W] B,H,W ----- ^{*2}	—/(ISBA5)[R/W] B,H,W ----- ^{*2}	
001838 _H	FCR15[R/W] B,H,W ---00100	FCR05[R/W] B,H,W -0000000	FBYTE5[R/W] B,H,W 00000000 00000000		
00183C _H	FTICR5[R/W] B,H,W 00000000 00000000		—	—	

*3: Reserved because CSIO mode is not set immediately after reset.

*4: Reserved because LIN2.1 mode is not set immediately after reset.

*1: Byte access is possible only for access to lower 8 bits.

*2: Reserved because I²C mode is not set immediately after reset.

*3: Reserved because CSIO mode is not set immediately after reset.

*4: Reserved because LIN2.1 mode is not set immediately after reset.

Address	Address offset value / Register name				Block
	+0	+1	+2	+3	
001D70 _H to 001FFC _H	—	—	—	—	Reserved
002000 _H	CTRLR0 [R/W] B,H,W ----- 000-0001		STATR0 [R/W] B,H,W ----- 00000000		CAN0 (128msb)
002004 _H	ERRCNT0 [R] B,H,W 00000000 00000000		BTR0 [R/W] B,H,W -0100011 00000001		
002008 _H	INTR0 [R] B,H,W 00000000 00000000		TESTR0 [R/W] B,H,W ----- X00000--		
00200C _H	BRPER0 [R/W] B,H,W ----- ----0000		—	—	
002010 _H	IF1CREQ0 [R/W] B,H,W 0----- 00000001		IF1CMSK0 [R/W] B,H,W ----- 00000000		
002014 _H	IF1MSK20 [R/W] B,H,W 11-11111 11111111		IF1MSK10 [R/W] B,H,W 11111111 11111111		
002018 _H	IF1ARB20 [R/W] B,H,W 00000000 00000000		IF1ARB10 [R/W] B,H,W 00000000 00000000		
00201C _H	IF1MCTR0 [R/W] B,H,W 00000000 0---0000		—	—	
002020 _H	IF1DTA10 [R/W] B,H,W 00000000 00000000		IF1DTA20 [R/W] B,H,W 00000000 00000000		
002024 _H	IF1DTB10 [R/W] B,H,W 00000000 00000000		IF1DTB20 [R/W] B,H,W 00000000 00000000		
002028 _H	—	—	—	—	
00202C _H	—	—	—	—	
002030 _H , 002034 _H	Reserved(IF1 data mirror)				
002038 _H	—	—	—	—	
00203C _H	—	—	—	—	
002040 _H	IF2CREQ0 [R/W] B,H,W 0----- 00000001		IF2CMSK0 [R/W] B,H,W ----- 00000000		
002044 _H	IF2MSK20 [R/W] B,H,W 11-11111 11111111		IF2MSK10 [R/W] B,H,W 11111111 11111111		
002048 _H	IF2ARB20 [R/W] B,H,W 00000000 00000000		IF2ARB10 [R/W] B,H,W 00000000 00000000		
00204C _H	IF2MCTR0 [R/W] B,H,W 00000000 0---0000		—	—	
002050 _H	IF2DTA10 [R/W] B,H,W 00000000 00000000		IF2DTA20 [R/W] B,H,W 00000000 00000000		

Interrupt factor	Interrupt number		Interrupt level	Offset	Default address for TBR	RN
	Decimal	Hexadecimal				
Multi-function serial interface ch.3 (transmission completed)	27	1B	ICR11	390 _H	000FFF90 _H	11
Multi-function serial interface ch.4 (reception completed)	28	1C	ICR12	38C _H	000FFF8C _H	12* ¹
Multi-function serial interface ch.4 (status)						
Multi-function serial interface ch.4 (transmission completed)	29	1D	ICR13	388 _H	000FFF88 _H	13
Multi-function serial interface ch.5 (reception completed)	30	1E	ICR14	384 _H	000FFF84 _H	14* ¹
Multi-function serial interface ch.5 (status)						
Multi-function serial interface ch.5 (transmission completed)	31	1F	ICR15	380 _H	000FFF80 _H	15
Multi-function serial interface ch.6 (reception completed)	32	20	ICR16	37C _H	000FFF7C _H	16* ¹
Multi-function serial interface ch.6 (status)						
Multi-function serial interface ch.6 (transmission completed)	33	21	ICR17	378 _H	000FFF78 _H	17
CAN0	34	22	ICR18	374 _H	000FFF74 _H	-
CAN1	35	23	ICR19	370 _H	000FFF70 _H	-
RAM diagnosis end						
RAM initialization completion						
Error generation during RAM diagnosis						
Backup RAM diagnosis end						
Backup RAM initialization completion						
Error generation during Backup RAM diagnosis						
CAN2	36	24	ICR20	36C _H	000FFF6C _H	-
Up/down counter 0						
Up/down counter 1						
Real time clock	37	25	ICR21	368 _H	000FFF68 _H	-
Multi-function serial interface ch.7 (reception completed)	38	26	ICR22	364 _H	000FFF64 _H	22* ¹
Multi-function serial interface ch.7 (status)						
16-bit Free-running timer 0 (0 detection) / (compare clear)	39	27	ICR23	360 _H	000FFF60 _H	23
Multi-function serial interface ch.7 (transmission completed)						
PPG 1/10/11/20/21/30/31	40	28	ICR24	35C _H	000FFF5C _H	24* ³
16-bit Free-run timer 1 (0 detection) / (compare clear)						
PPG 2/3/12/13/23/32/43	41	29	ICR25	358 _H	000FFF58 _H	25* ³
16-bit Free-run timer 2 (0 detection) / (compare clear)						
PPG 4/5/14/15/24/25/35/44	42	2A	ICR26	354 _H	000FFF54 _H	26* ³
PPG 6/7/16/17/26/27/37	43	2B	ICR27	350 _H	000FFF50 _H	27* ³
PPG 8/9/18/19/28/29	44	2C	ICR28	34C _H	000FFF4C _H	28* ³

(4-1-3) Bit setting: SMR : MD2=0, SMR:MD1=1, SMR : MD0=0, SMR:SCINV=0, SCR:SPI=1

(TA:-40°C to +125°C, V_{CC}=AV_{CC}=5.0V±10%/V_{CC}=AV_{CC}=3.3V±0.3V, V_{SS}=AV_{SS}=0.0V)

Parameter	Symbol	Pin name	Conditions	Value		Unit	Remarks
				Min	Max		
Serial clock cycle time	t _{SCYC}	SCK0 to SCK11	-	4t _{CPP}	-	ns	Internal shift clock mode output pin : C _L =50pF
SCK ↑ → SOT delay time	t _{SHOVI}	SCK0 to SCK2, SCK5 to SCK11 SOT0 to SOT2, SOT5 to SOT11		-30	30	ns	
		SCK3 , SCK4 SOT3 , SOT4		-300	300	ns	
Valid SIN → SCK ↓ setup time	t _{IVSLI}	SCK0 to SCK2, SCK5 to SCK11 SIN0 to SIN2, SIN5 to SIN11		34	-	ns	
		SCK3 , SCK4 SIN3 , SIN4		300	-	ns	
SCK ↓ → Valid SIN hold time	t _{SLIXI}	SCK0 to SCK11 SIN0 to SIN11		0	-	ns	
SOT→SCK↓ delay time	t _{SOVLI}	SCK0 to SCK11 SOT0 to SOT11		2t _{CPP} -30	-	ns	
Serial clock "H"pulse width	t _{SHSL}	SCK0 to SCK11	-	t _{CPP} + 10	-	ns	External shift clock mode output pin: C _L =50pF
Serial clock "L" pulse width	t _{SLSH}			2t _{CPP} -10	-	ns	
SCK ↑ → SOT delay time	t _{SHOVE}	SCK0 to SCK2, SCK5 to SCK11 SOT0 to SOT2, SOT5 to SOT11		-	33	ns	
		SCK3 , SCK4 SOT3 , SOT4		-	300	ns	
Valid SIN → SCK ↓ setup time	t _{IVSHE}	SCK0 to SCK11 SIN0 to SIN11		10	-	ns	
SCK ↓ → Valid SIN hold time	t _{SLIXE}			20	-	ns	
SCK fall time	t _F	SCK0 to SCK11		-	5	ns	
SCK rise time	t _R	SCK0 to SCK11		-	5	ns	

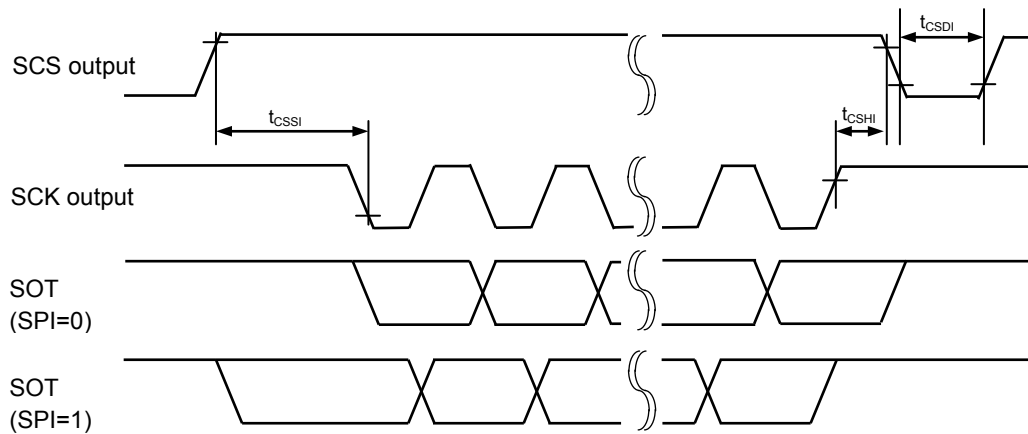
Notes:

AC characteristic in CLK synchronized mode.

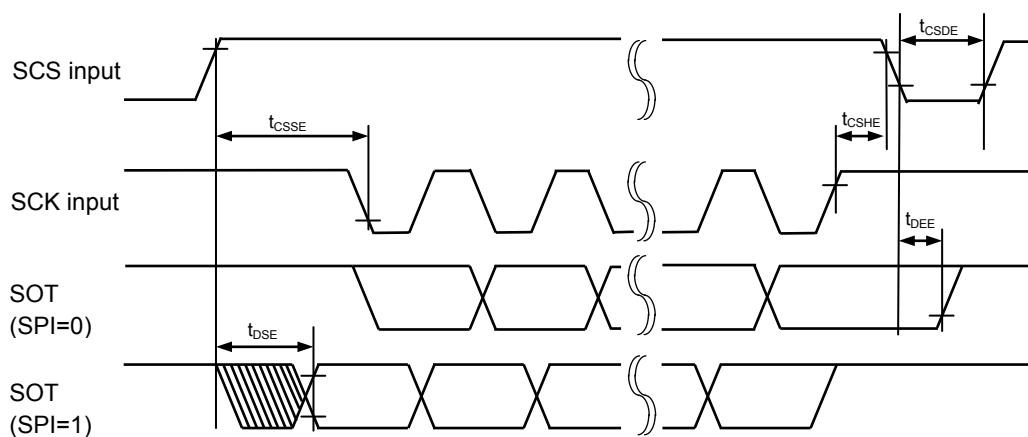
C_L is the load capacitance applied to pins during testing.

The maximum baud rate is limited by internal operation clock used and other parameters. Please use ch.3 and ch.4 with maximum baud rate 400kbps or less.

See Hardware Manual for details.



When Serial chip select is used , Serial clock output mark level "H",
Serial chip select Inactive level "L"
Internal shift clock mode



When Serial chip select is used , Serial clock output mark level "H",
Serial chip select Inactive level "L"
External shift clock mode

(4-1-8) Bit setting: SMR:MD2=0, SMR:MD1=1, SMR:MD0=0,

When Serial chip select is used: SCSCR:CSEN=1,

Serial clock output mark level "L" : SMR,SCSFR:SCINV=1,

Serial chip select Inactive level "L" : SCSCR,SCSFR:CSLVL=0

(T_A: -40°C to +125°C, V_{CC}=AV_{CC}=5.0V±10%/V_{CC}=AV_{CC}=3.3V±0.3V, V_{SS}=AV_{SS}=0.0V)

Parameter	Symbol	Pin name	Conditions	Value		Unit	Remarks
				Min	Max		
SCS↑→SCK↑ setup time	t _{CSSI}	SCK1 , SCK2, SCK5 to SCK11 SCS1 , SCS2, SCS50 to SCS53, SCS60 to SCS63, SCS70 to SCS73, SCS8 to SCS11	-	t _{CSSU} -50 *1	t _{CSSU} +0 *1	ns	Internal shift clock mode output pin : C _L =50pF
		SCK3 , SCK4 SCS3 , SCS40 to SCS43		t _{CSSU} -50 *1	t _{CSSU} +300 *1	ns	
SCK↓→SCS↓ hold time	t _{CSHI}	SCK1 , SCK2, SCK5 to SCK11 SCS1 , SCS2, SCS50 to SCS53, SCS60 to SCS63, SCS70 to SCS73, SCS8 to SCS11		t _{CSHD} -10 *2	t _{CSHD} +50 *2	ns	
		SCK3 , SCK4 SCS3 , SCS40 to SCS43		t _{CSHD} -300 *2	t _{CSHD} +50 *2	ns	
SCS deselect time	t _{CSDI}	SCS1 to SCS3, SCS40 to SCS43, SCS50 to SCS53, SCS60 to SCS63, SCS70 to SCS73, SCS8 to SCS11		t _{CSDS} -50 *3	t _{CSDS} +50 *3	ns	

Flash memory
(1) Electrical Characteristics

Parameter	Value			Unit	Remarks
	Min	Typ	Max		
Sector erase time	–	200	800	ms	8 Kbytes sector* ¹ , excluding internal preprogramming time
	–	300	1100	ms	8 Kbytes sector* ¹ , including internal preprogramming time
	–	400	2000	ms	64 Kbytes sector* ¹ , excluding internal preprogramming time
	–	700	3700	ms	64 Kbytes sector* ¹ , including internal preprogramming time
8-bit writing time	–	9	288	μs	Exclusive of overhead time at system level* ¹
16-bit writing time	–	12	384	μs	Exclusive of overhead time at system level* ¹
ECC writing time	–	9	288	μs	Exclusive of overhead time at system level* ¹
Erase cycle* ² / Data retain time	1,000 cycles/ 20 years, 10,000 cycles/ 10 years, 100,000 cycles/ 5 years	–	–	–	Average T _A =+85°C* ³

*1: The guaranteed value for erasure up to 100,000 cycles.

*2: Number of erase cycles for each sector.

*3: This value comes from the technology qualification (using Arrhenius equation to translate high temperature measurements into normalized value at + 85°C).

(2) Notes

While the Flash memory is written or erased, shutdown of the external power (V_{CC}) is prohibited.

In the application system where V_{CC} might be shut down while writing or erasing, be sure to turn the power off by using an external voltage detection function.

To put it concretely, after the external power supply voltage falls below the detection voltage (V_{DL}*), hold V_{CC} at 2.7V or more within the duration calculated by the following expression:

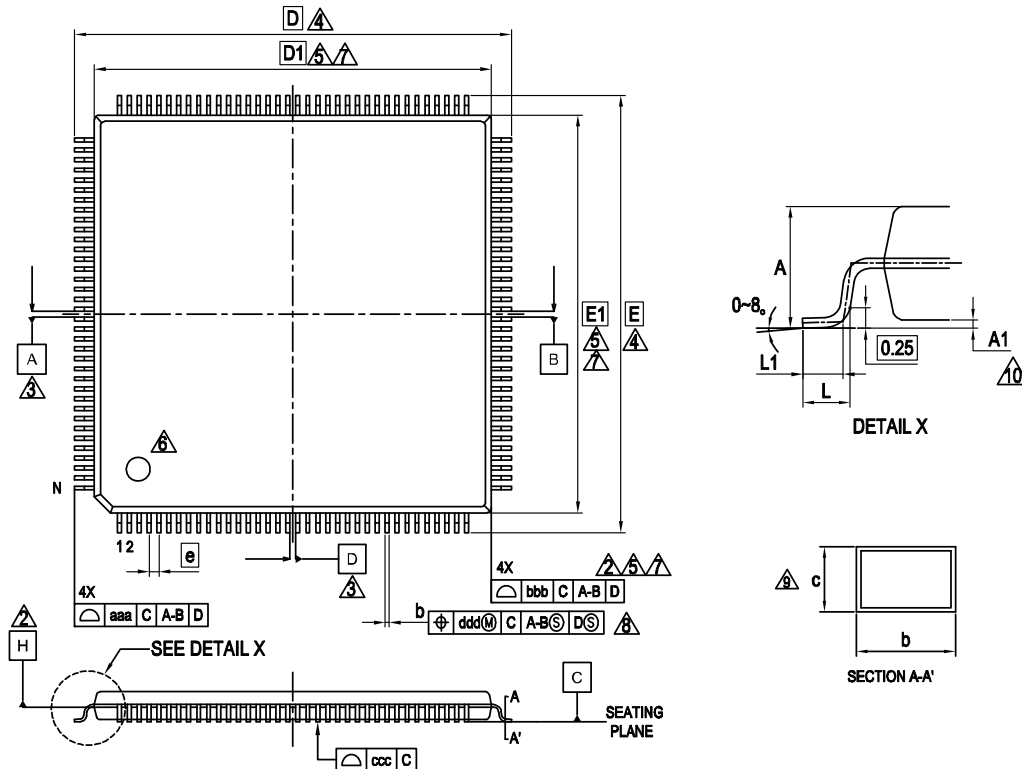
$$T_d^*[\mu s] + (\text{period of PCLK} [\mu s] \times 257) + 50 [\mu s]$$

*: See "4.AC Characteristics (8) Low-voltage detection (External low-voltage detection) "

Part number	Sub clock	CSV Initial value	LVD Initial value	Package*2
MB91F526KWBPMP1	Yes	ON	ON	LQN • 144 pin, (Lead pitch 0.4mm) Plastic
MB91F526KYBPMP1			OFF	
MB91F526KJBPM1		OFF	ON	
MB91F526KLBPM1			OFF	
MB91F525KWBPMP1		ON	ON	
MB91F525KYBPMP1			OFF	
MB91F525KJBPM1		OFF	ON	
MB91F525KLBPM1			OFF	
MB91F524KWBPMP1		ON	ON	
MB91F524KYBPMP1			OFF	
MB91F524KJBPM1		OFF	ON	
MB91F524KLBPM1			OFF	
MB91F523KWBPMP1		ON	ON	
MB91F523KYBPMP1			OFF	
MB91F523KJBPM1		OFF	ON	
MB91F523KLBPM1			OFF	
MB91F522KWBPMP1		ON	ON	
MB91F522KYBPMP1			OFF	
MB91F522KJBPM1		OFF	ON	
MB91F522KLBPM1			OFF	
MB91F526KSBPM1	None	ON	ON	
MB91F526KUBPM1			OFF	
MB91F526KHBPM1		OFF	ON	
MB91F526KKBPM1			OFF	
MB91F525KSBPM1		ON	ON	
MB91F525KUBPM1			OFF	
MB91F525KHBPM1		OFF	ON	
MB91F525KKBPM1			OFF	
MB91F524KSBPM1		ON	ON	
MB91F524KUBPM1			OFF	
MB91F524KHBPM1		OFF	ON	
MB91F524KKBPM1			OFF	
MB91F523KSBPM1		ON	ON	
MB91F523KUBPM1			OFF	
MB91F523KHBPM1		OFF	ON	
MB91F523KKBPM1			OFF	
MB91F522KSBPM1		ON	ON	
MB91F522KUBPM1			OFF	
MB91F522KHBPM1		OFF	ON	
MB91F522KKBPM1			OFF	

Part number	Sub clock	CSV Initial value	LVD Initial value	Package*
MB91F526FWEPMC	Yes	ON	ON	LQI • 100 pin, Plastic
MB91F526FJEPMC		OFF	ON	
MB91F525FWEPMC		ON	ON	
MB91F525FJEPMC		OFF	ON	
MB91F524FWEPMC		ON	ON	
MB91F524FJEPMC		OFF	ON	
MB91F523FWEPMC		ON	ON	
MB91F523FJEPMC		OFF	ON	
MB91F522FWEPMC		ON	ON	
MB91F522FJEPMC		OFF	ON	
MB91F526FSEPMC	None	ON	ON	
MB91F526FHEPMC		OFF	ON	
MB91F525FSEPMC		ON	ON	
MB91F525FHEPMC		OFF	ON	
MB91F524FSEPMC		ON	ON	
MB91F524FHEPMC		OFF	ON	
MB91F523FSEPMC		ON	ON	
MB91F523FHEPMC		OFF	ON	
MB91F522FSEPMC		ON	ON	
MB91F522FHEPMC		OFF	ON	
MB91F526DWEPMC	Yes	ON	ON	LQH • 80 pin, Plastic
MB91F526DJEPMC		OFF	ON	
MB91F525DWEPMC		ON	ON	
MB91F525DJEPMC		OFF	ON	
MB91F524DWEPMC		ON	ON	
MB91F524DJEPMC		OFF	ON	
MB91F523DWEPMC		ON	ON	
MB91F523DJEPMC		OFF	ON	
MB91F522DWEPMC		ON	ON	
MB91F522DJEPMC		OFF	ON	
MB91F526DSEPMC	None	ON	ON	
MB91F526DHEPMC		OFF	ON	
MB91F525DSEPMC		ON	ON	
MB91F525DHEPMC		OFF	ON	
MB91F524DSEPMC		ON	ON	
MB91F524DHEPMC		OFF	ON	
MB91F523DSEPMC		ON	ON	
MB91F523DHEPMC		OFF	ON	
MB91F522DSEPMC		ON	ON	
MB91F522DHEPMC		OFF	ON	

LQS144 , 144 Lead Plastic Low Profile Quad Flat Package

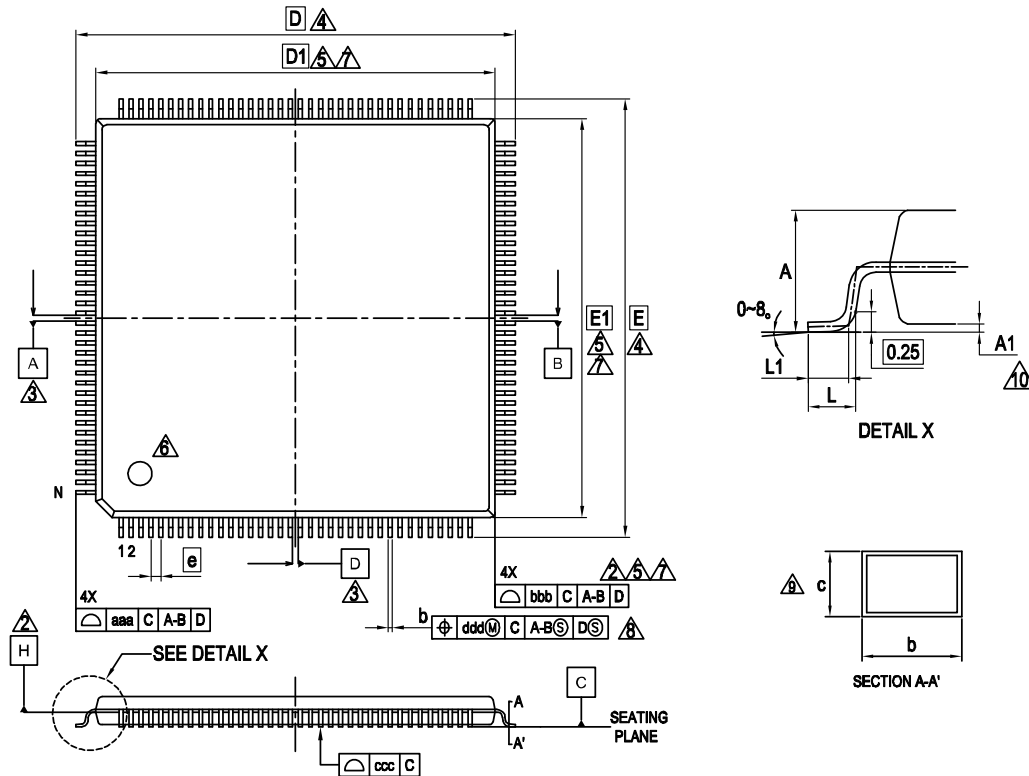


PACKAGE	LQS144		
SYMBOL	MIN.	NOM.	MAX.
A	—	—	1.70
A1	0.08	—	0.28
b	0.17	0.22	0.27
c	0.09	—	0.20
D	22.00 BSC.		
D1	20.00 BSC.		
e	0.50 BSC.		
E	22.00 BSC.		
E1	20.00 BSC.		
L	0.45	0.60	0.75
L1	0.30	0.50	0.70
aaa	—	—	0.20
bbb	—	—	0.10
ccc	—	—	0.08
ddd	—	—	0.08
N	144		

NOTES

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (mm)
2. DATUM PLANE H IS LOCATED AT THE BOTTOM OF THE MOLD PARTING LINE COINCIDENT WITH WHERE THE LEAD EXITS THE BODY.
3. DATUMS A-B AND D TO BE DETERMINED AT DATUM PLANE H.
4. TO BE DETERMINED AT SEATING PLANE C.
5. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PRE SIDE. DIMENSIONS D1 AND E1 INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
6. DETAILS OF PIN 1 IDENTIFIER ARE OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED.
7. REGARDLESS OF THE RELATIVE SIZE OF THE UPPER AND LOWER BODY SECTIONS, DIMENSIONS D1 AND E1 ARE DETERMINED AT THE LARGEST FEATURE OF THE BODY EXCLUSIVE OF MOLD FLASH AND GATE BURRS, BUT INCLUDING ANY MISMATCH BETWEEN THE UPPER AND LOWER SECTIONS OF THE MOLDER BODY.
8. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. THE DAMBAR PROTRUSION (S) SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED b MAXIMUM BY MORE THAN 0.08mm. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE LEAD FOOT.
9. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm AND 0.25mm FROM THE LEAD TIP.
10. A1 IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.

LQN144 , 144 Lead Plastic Low Profile Quad Flat Package



PACKAGE	LQN144		
SYMBOL	MIN.	NOM.	MAX.
A	—	—	1.70
A1	0.05	—	0.15
b	0.145	0.18	0.215
c	0.115	—	0.195
D	18.00 BSC.		
D1	16.00 BSC.		
e	0.40 BSC.		
E	18.00 BSC.		
E1	16.00 BSC.		
L	0.45	0.60	0.75
L1	0.30	0.50	0.70
aaa	—	—	0.20
bbb	—	—	0.10
ccc	—	—	0.08
ddd	—	—	0.07
N	144		

NOTES

- CONTROLLING DIMENSIONS ARE IN MILLIMETERS (mm)
- DATUM PLANE H IS LOCATED AT THE BOTTOM OF THE MOLD PARTING LINE COINCIDENT WITH WHERE THE LEAD EXITS THE BODY.
- DATUMS A-B AND D TO BE DETERMINED AT DATUM PLANE H.
- TO BE DETERMINED AT SEATING PLANE C.
- DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PRE SIDE. DIMENSIONS D1 AND E1 INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
- DETAILS OF PIN 1 IDENTIFIER ARE OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED.
- REGARDLESS OF THE RELATIVE SIZE OF THE UPPER AND LOWER BODY SECTIONS, DIMENSIONS D1 AND E1 ARE DETERMINED AT THE LARGEST FEATURE OF THE BODY EXCLUSIVE OF MOLD FLASH AND GATE BURRS, BUT INCLUDING ANY MISMATCH BETWEEN THE UPPER AND LOWER SECTIONS OF THE MOLDER BODY.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. THE DAMBAR PROTRUSION (S) SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED b MAXIMUM BY MORE THAN 0.08mm. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE LEAD FOOT.
- THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm AND 0.25mm FROM THE LEAD TIP.
- A1 IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.

■ Scope of Impact

For the affected parts, when the Power-On Reset and Internal Low Voltage Detection are not generated, the MCU may set invalid package and sub clock option information. Therefore, the MCU may operate with an invalid pin configuration.

■ Workaround

For the affected parts, it is necessary to satisfy at least one of the Power-On Reset requirements for any Power-On event as given below:

- (1) The VCC voltage is less than 200 mV for 50 ms or longer (t_{OFF})
- (2) VCC Power ramp rate is less than 4 mV/ μ s (dV/dt) until a voltage level for a safe Power-On detection is reached
- (3) C-pin voltage is below 60 mV when VCC is turned on again

If the customer system does not satisfy the condition above-mentioned, Cypress will release new version D, so Cypress recommends the version D for MB91F52x. The new version prevents the limitation when an external reset signal is asserted at pin RSTX anytime the supply voltage (VCC) is turned on.

■ Fix Status

Will be fixed in production silicon version D, E

2. Limitation for Watch mode (power off)

■ Problem Definition

If the below all trigger conditions (1) to (3) are satisfied, the below registers will be initialized after MCU recovers from watch mode (power off).

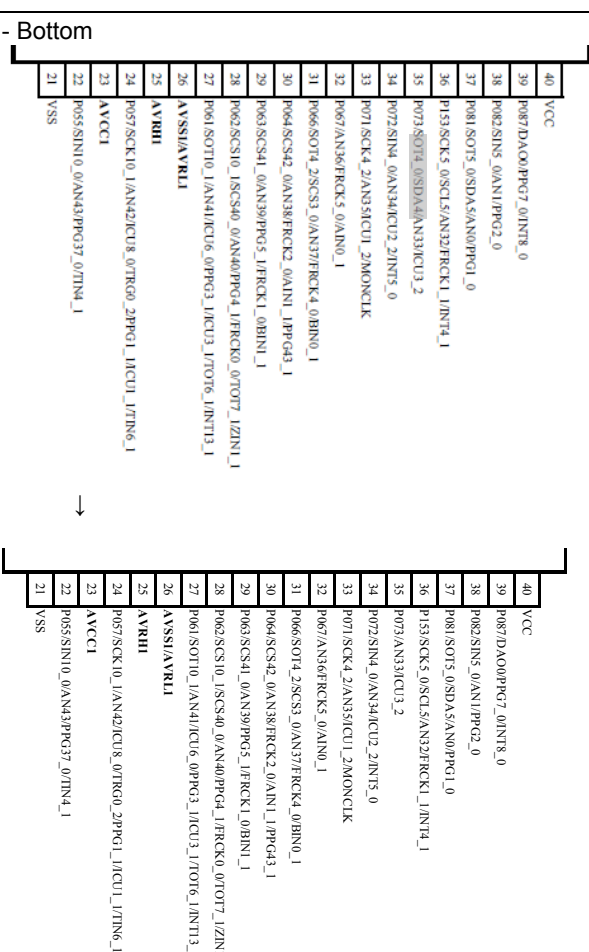
■ Trigger Conditions

- (1) Using the watch mode (power off)
 - (2) Interrupt levels that are used as sources for recovering from the watch mode (power off) are '16' to '30', or using NMIX pin as source for recovering from the watch mode (power off)
 - (3) The sources for recovering from the watch mode (power off) are generated between PCLK 1 cycle and PMUCLK 3 cycles (*), after CPU state changes to the watch mode (power off)
- (*): In case of PCLK = 0.5 MHz and PMUCLK = 32 kHz, it is approx. 2 μ s to 100 μ s

■ Scope of Impact

If the all trigger conditions (1) to (3) are satisfied, the below registers will be initialized after MCU recovers from watch mode (power off).

WTCRH, WTCRM, WTCRL
CSELR.SCEN
CMONR.SCRDY
CCRTSEL.R.CST
CCRTSEL.R.CSC

Page	Section	Change Results
14	■ Pin Assignment MB91F52xD	- Bottom 

Page	Section	Change Results
19	■PIN Description	(Continued) (Correct)

Page	Section	Change Results
46	■ During Power-on	The following sentence modified as following: (Error) To prevent a malfunction of the voltage step-down circuit built in the device, the voltage rising must be monotonic increasing during power-on. Power-on prohibits that the voltage goes up and down and voltage rising stops temporarily. (Correct) To prevent a malfunction of the voltage step-down circuit built in the device, the voltage rising must be monotonic during power-on.
142, 143	11. Electrical Characteristics Recommended operating conditions	The following sentence modified as following: (Error) *1: When it is used outside recommended operation guarantee range (range of the operation guarantee), contact your sales representative. Moreover, minimum value with an effective external low-voltage detection reset becomes a voltage until generating low-voltage detection reset. (Correct) *1: When it is used outside recommended operation guarantee range (range of the operation guarantee), contact your sales representative. Detection voltage of the external low voltage detection reset (initial) is 2.8V±8% (2.576V to 3.024V). This detection voltage (2.576V) is below the minimum operation guarantee voltage (2.7V). Between this detection voltage and the minimum operation guarantee voltage, MCU functions are not guaranteed except for the low voltage detector. Note that although the detection level is below the minimum operation guarantee voltage, the LVD reset factor flag is set as the voltage drops below the detection level.
156, 157	11. Electrical Characteristics AC Characteristics	Added (3-2) Power-on Conditions for MB91F52xxxE